



HERAF1601G - HERAF1608G

Isolated 16.0 AMPS.

Glass Passivated High Efficient Rectifiers

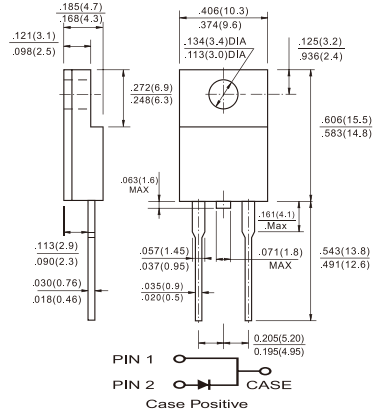
ITO-220AC

Features

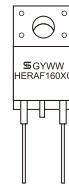
- ◇ UL Recognized File # E-326243
- ◇ Glass passivated chip junction.
- ◇ High efficiency, Low VF
- ◇ High current capability
- ◇ High reliability
- ◇ High surge current capability
- ◇ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application.
- ◇ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ◇ Cases: ITO-220AC molded plastic
- ◇ Epoxy: UL 94V0 rate flame retardant
- ◇ Terminals: Pure tin plated, lead free solderable per MIL-STD-202, Method 208 guaranteed
- ◇ Polarity: As marked
- ◇ High temperature soldering guaranteed: 260°C/10 seconds 0.25", (6.35mm) from case.
- ◇ Mounting torque : 5 in – 1bs. max.
- ◇ Weight: 2.24 grams



Dimensions in inches and (millimeters)
Marking Diagram



HERAF160XG= Specific Device Code
G = Green Compound
Y = Year
WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| Type Number | Symbol | HERAF 1601G | HERAF 1602G | HERAF 1603G | HERAF 1604G | HERAF 1605G | HERAF 1606G | HERAF 1607G | HERAF 1608G | Units | |
|---|--------------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|----------|----|
| Maximum Recurrent Peak Reverse Voltage | VRRM | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V | |
| Maximum RMS Voltage | VRMS | 35 | 70 | 140 | 210 | 280 | 420 | 560 | 700 | V | |
| Maximum DC Blocking Voltage | VDC | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V | |
| Maximum Average Forward Rectified Current @T _C =100°C | I _{F(AV)} | 16 | | | | | | | | A | |
| Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I _{FSM} | 250 | | | | | | | | A | |
| Maximum Instantaneous Forward Voltage @16.0A | V _F | 1.0 | | 1.3 | | 1.7 | | | V | | |
| Maximum DC Reverse Current at Rated DC Blocking Voltage @T _A =25°C (Note 1) @ T _A =125°C | I _R | 10 | | | | 400 | | | | uA uA | |
| Maximum Reverse Recovery Time (Note 4) | T _{rr} | 50 | | | | | 80 | | | | nS |
| Typical Junction Capacitance (Note 2) | C _j | 150 | | | | | 110 | | | | pF |
| Typical Thermal Resistance (Note 3) | R _{θJC} | 2.0 | | | | | | | | °C/W | |
| Operating Temperature Range | T _J | -65 to +150 | | | | | | | | °C | |
| Storage Temperature Range | T _{STG} | -65 to +150 | | | | | | | | °C | |

- Notes:
1. Pulse Test with PW=300 usec, 1% Duty Cycle
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D. C.
 3. Mounted on Heatsink Size of 2 in x 3 in x 0.25 in Al-Plate.
 4. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

RATINGS AND CHARACTERISTIC CURVES (HERAF1601G THRU HERAF1608G)

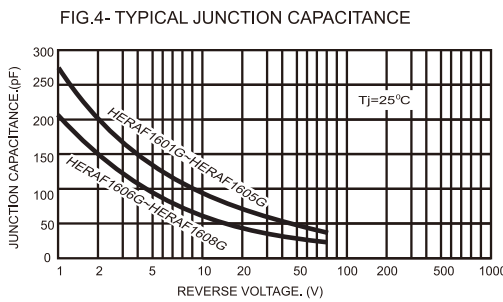
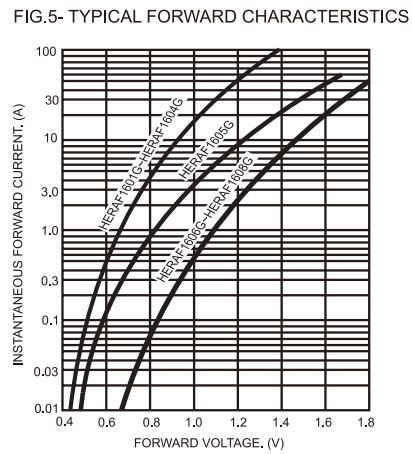
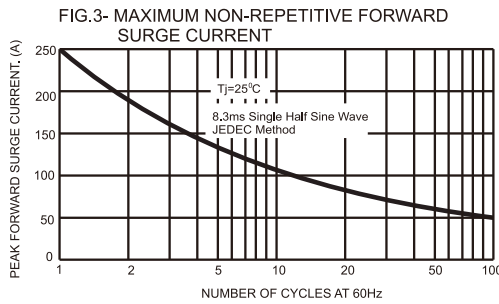
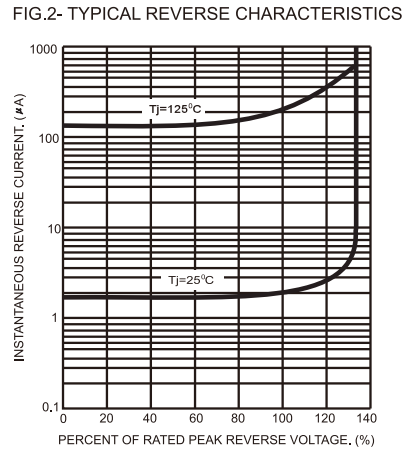
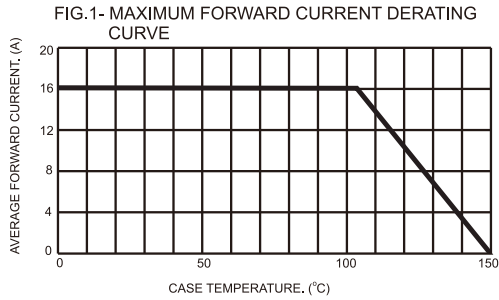
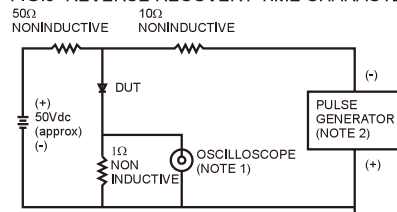


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance= 1 megohm 22pf
 2. Rise Times=10ns max. Source Impedance= 50 ohms

